74LVC16374A-Q100; 74LVCH16374A-Q100

16-bit edge-triggered D-type flip-flop; 5 V tolerant; 3-state

Rev. 1 — 28 January 2013 Product data sheet

1. General description

The 74LVC16374A-Q100 and 74LVCH16374A-Q100 are 16-bit edge-triggered flip-flops featuring separate D-type inputs with bus hold (74LVCH16374A-Q100 only) for each flip-flop and 3-state outputs for bus-oriented applications. It consists of two sections of eight positive edge-triggered flip-flops. A clock input (nCP) and an output enable ($\overline{nOE}$) are provided for each octal. The flip-flops store the state of their individual D-inputs that meet the set-up and hold time requirements on the LOW-to-HIGH clock (CP) transition.

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When pin $\overline{nOE}$ is LOW, the contents of the flip-flops are available at the outputs. When pin $\overline{nOE}$ is HIGH, the outputs go to the high-impedance OFF-state. Operation of input $\overline{nOE}$ does not affect the state of the flip-flops. Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices in mixed 3.3 V and 5 V applications. Bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from −40 °C to +85 °C and from −40 °C to +125 °C
- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Multibyte flow-through standard pinout architecture
- Low inductance multiple supply pins for minimum noise and ground bounce
- Direct interface with TTL levels
- All data inputs have bus hold (74LVCH16374A-Q100 only)
- High-impedance outputs when V_{CC} = 0 V
- Complies with JEDEC standard:
  - JESD8-7A (1.65 V to 1.95 V)
  - JESD8-5A (2.3 V to 2.7 V)
  - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:

- MIL-STD-883, method 3015 exceeds 2000 V
- HBM JESD22-A114F exceeds 2000 V
- MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LVC16374ADGG-Q100	−40 °C to +125 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1
74LVCH16374ADGG-Q100				

4. Functional diagram

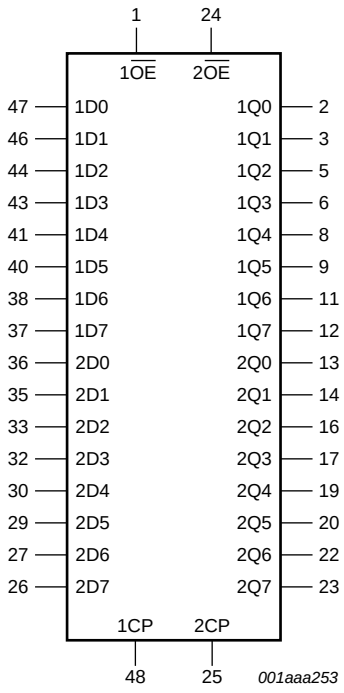


Fig 1. Logic symbol

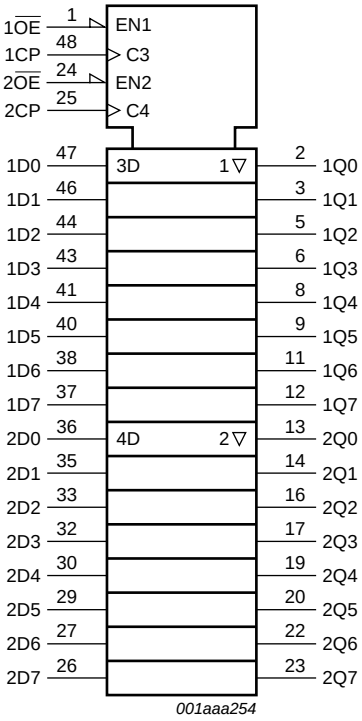


Fig 2. IEC logic symbol

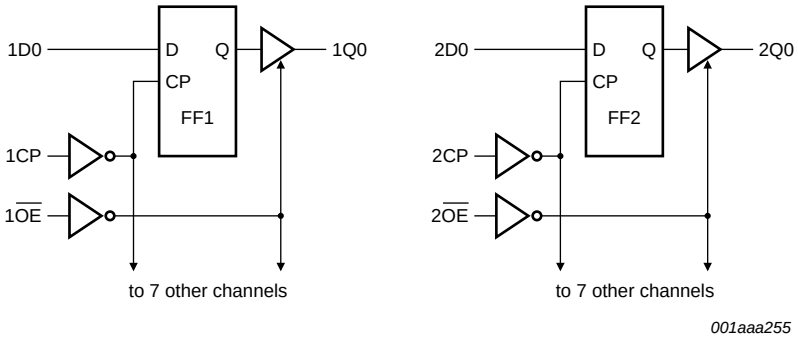


Fig 3. Logic diagram

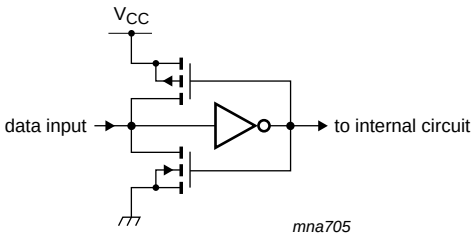


Fig 4. Bus hold circuit

5. Pinning information

5.1 Pinning

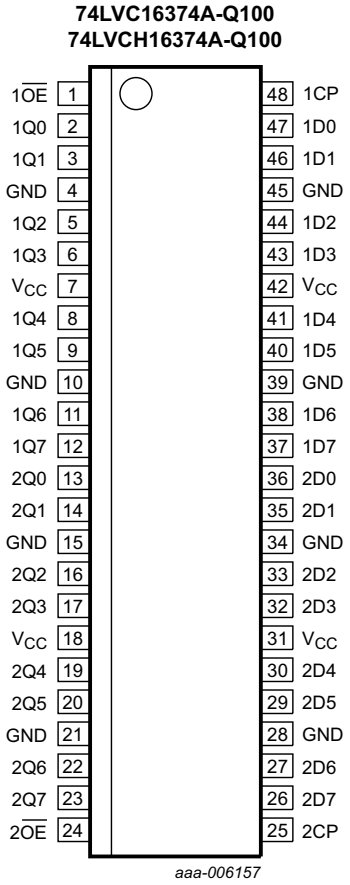


Fig 5. Pin configuration SOT362-1 (TSSOP48)

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$1\overline{OE}$, $2\overline{OE}$	1, 24	output enable input (active LOW)
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V_{CC}	7, 18, 31, 42	supply voltage
1Q0 to 1Q7	2, 3, 5, 6, 8, 9, 11, 12	data output
2Q0 to 2Q7	13, 14, 16, 17, 19, 20, 22, 23	data output
1D0 to 1D7	47, 46, 44, 43, 41, 40, 38, 37	data input
2D0 to 2D7	36, 35, 33, 32, 30, 29, 27, 26	data input
1CP, 2CP	48, 25	clock input

6. Functional description

Table 3. Function selection[1]

Operating mode	Input			Internal flip-flop	Output nQ0 to nQ7
	$n\overline{OE}$	nCP	nDn		
Load and read register	L	↑	l	L	L
	L	↑	h	H	H
Load register and disable outputs	H	↑	l	L	Z
	H	↑	h	H	Z

[1] H = HIGH voltage level;
h = HIGH voltage level one set-up time prior to the HIGH-to-LOW CP transition;
L = LOW voltage level;
l = LOW voltage level one set-up time prior to the HIGH-to-LOW CP transition;
↑ = LOW-to-HIGH transition;
Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			–0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$ V		–50	-	mA
V_I	input voltage		[1]	–0.5	+6.5	V
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V		-	±50	mA
V_O	output voltage	output HIGH-or LOW-state	[2]	–0.5	V_{CC} + 0.5	V
		output 3-state	[2]	–0.5	+6.5	V
I_O	output current	V_O = 0 V to V_{CC}		-	±50	mA
I_{CC}	supply current			-	100	mA
I_{GND}	ground current			–100	-	mA
T_{stg}	storage temperature			–65	+150	°C

Table 4. Limiting values *...continued*

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
P_{tot}	total power dissipation	T_{amb} = −40 °C to +125 °C	[3]	-	500	mW

[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

[2] The output voltage ratings may be exceeded if the output current ratings are observed.

[3] Above 60 °C, the value of P_{tot} derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
V_I	input voltage		0	-	5.5	V
V_O	output voltage	active mode	0	-	V_{CC}	V
		power-down mode; V_{CC} = 0 V	0	-	5.5	V
T_{amb}	ambient temperature		−40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	0	-	20	ns/V
		V_{CC} = 2.7 V to 3.6 V	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	−40 °C to +85 °C			−40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V_{CC} = 1.2 V	1.08	-	-	1.08	-	V
		V_{CC} = 1.65 V to 1.95 V	0.65 × V_{CC}	-	-	0.65 × V_{CC}	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.2 V	-	-	0.12	-	0.12	V
		V_{CC} = 1.65 V to 1.95 V	-	-	0.35 × V_{CC}	-	0.35 × V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}						
		I_O = −100 μA; V_{CC} = 1.65 V to 3.6 V	V_{CC} − 0.2	V_{CC}	-	V_{CC} − 0.3	-	V
		I_O = −4 mA; V_{CC} = 1.65 V	1.2	-	-	1.05	-	V
		I_O = −8 mA; V_{CC} = 2.3 V	1.8	-	-	1.65	-	V
		I_O = −12 mA; V_{CC} = 2.7 V	2.2	-	-	2.05	-	V
		I_O = −18 mA; V_{CC} = 3.0 V	2.4	-	-	2.25	-	V
		I_O = −24 mA; V_{CC} = 3.0 V	2.2	-	-	2.0	-	V

Table 6. Static characteristics *…continued*

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		I_O = 100 μA; V_{CC} = 1.65 V to 3.6 V	-	0	0.2	-	0.3	V
		I_O = 4 mA; V_{CC} = 1.65 V	-	-	0.45	-	0.65	V
		I_O = 8 mA; V_{CC} = 2.3 V	-	-	0.6	-	0.8	V
		I_O = 12 mA; V_{CC} = 2.7 V	-	-	0.4	-	0.6	V
		I_O = 24 mA; V_{CC} = 3.0 V	-	-	0.55	-	0.8	V
I_I	input leakage current	V_{CC} = 3.6 V; V_I = 5.5 V or GND [2]	-	±0.1	±5	-	±20	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; V_{CC} = 3.6 V; V_O = 5.5 V or GND [2]	-	±0.1	±5	-	±20	μA
I_{OFF}	power-off leakage current	V_{CC} = 0 V; V_I or V_O = 5.5 V	-	±0.1	±10	-	±20	μA
I_{CC}	supply current	V_{CC} = 3.6 V; $V_I = V_{CC}$ or GND; I_O = 0 A	-	0.1	20	-	80	μA
ΔI_{CC}	additional supply current	per input pin; V_{CC} = 2.7 V to 3.6 V; $V_I = V_{CC} - 0.6$ V; I_O = 0 A	-	5	500	-	5000	μA
C_I	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND to V_{CC}	-	5.0	-	-	-	pF
I_{BHL}	bus hold LOW current	V_{CC} = 1.65; V_I = 0.58 V [3][4]	10	-	-	10	-	μA
		V_{CC} = 2.3; V_I = 0.7 V	30	-	-	25	-	μA
		V_{CC} = 3.0; V_I = 0.8 V	75	-	-	60	-	μA
I_{BHH}	bus hold HIGH current	V_{CC} = 1.65; V_I = 1.07 V [3][4]	–10	-	-	–10	-	μA
		V_{CC} = 2.3; V_I = 1.7 V	–30	-	-	–25	-	μA
		V_{CC} = 3.0; V_I = 2.0 V	–75	-	-	–60	-	μA
I_{BHLO}	bus hold LOW overdrive current	V_{CC} = 1.95 V [3][5]	200	-	-	200	-	μA
		V_{CC} = 2.7 V	300	-	-	300	-	μA
		V_{CC} = 3.6 V	500	-	-	500	-	μA

Table 6. Static characteristics *…continued*

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
I_{BHHO}	bus hold HIGH overdrive current	V_{CC} = 1.95 V [3][5]	–200	-	-	–200	-	µA
		V_{CC} = 2.7 V	–300	-	-	–300	-	µA
		V_{CC} = 3.6 V	–500	-	-	–500	-	µA

[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

[2] The bus hold circuit is switched off when $V_I > V_{CC}$ allowing 5.5 V on the input pin.

[3] Valid for data inputs (74LVCH16374A-Q100) only; control inputs do not have a bus hold circuit.

[4] The specified sustaining current at the data inputs holds the input below the specified V_I level.

[5] The specified overdrive current at the data input forces the data input to the opposite logic input state.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 9.

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	nCP to nQn; see Figure 6 [2]						
		V_{CC} = 1.2 V	-	14	-	-	-	ns
		V_{CC} = 1.65 V to 1.95 V	2.1	6.9	13.5	2.1	15.6	ns
		V_{CC} = 2.3 V to 2.7 V	1.5	3.7	6.7	1.5	7.7	ns
		V_{CC} = 2.7 V	1.5	3.4	6.0	1.5	7.5	ns
		V_{CC} = 3.0 V to 3.6 V	1.5	3.1	5.4	1.5	7.0	ns
t_{en}	enable time	$n\overline{OE}$ to nQn; see Figure 8 [2]						
		V_{CC} = 1.2 V	-	20	-	-	-	ns
		V_{CC} = 1.65 V to 1.95 V	1.5	5.9	13.1	1.5	15.1	ns
		V_{CC} = 2.3 V to 2.7 V	1.5	3.4	6.9	1.5	8.0	ns
		V_{CC} = 2.7 V	1.5	3.6	6.0	1.5	7.5	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	2.7	5.2	1.0	6.5	ns
t_{dis}	disable time	$n\overline{OE}$ to nQn; see Figure 6 [2]						
		V_{CC} = 1.2 V	-	12	-	-	-	ns
		V_{CC} = 1.65 V to 1.95 V	2.8	4.6	9.1	2.8	10.5	ns
		V_{CC} = 2.3 V to 2.7 V	1.0	2.5	4.9	1.0	5.7	ns
		V_{CC} = 2.7 V	1.5	3.4	5.1	1.5	6.5	ns
		V_{CC} = 3.0 V to 3.6 V	1.5	3.1	4.9	1.5	6.5	ns
t_W	pulse width	nCP HIGH; see Figure 6						
		V_{CC} = 1.65 V to 1.95 V	5.0	-	-	5.0	-	ns
		V_{CC} = 2.3 V to 2.7 V	4.0	-	-	4.0	-	ns
		V_{CC} = 2.7 V	3.0	-	-	3.0	-	ns
		V_{CC} = 3.0 V to 3.6 V	3.0	1.5	-	3.0	-	ns

Table 7. Dynamic characteristics *...continued*

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 9.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{su}	set-up time	nDn to nCP; see Figure 7							
		V_{CC} = 1.65 V to 1.95 V		4.0	-	-	4.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		3.0	-	-	3.0	-	ns
		V_{CC} = 2.7 V		1.9	-	-	1.9	-	ns
		V_{CC} = 3.0 V to 3.6 V		1.9	0.3	-	1.9	-	ns
t_h	hold time	nDn to nCP; see Figure 7							
		V_{CC} = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		2.5	-	-	2.5	-	ns
		V_{CC} = 2.7 V		1.1	-	-	1.1	-	ns
		V_{CC} = 3.0 V to 3.6 V		1.5	–0.3	-	1.5	-	ns
f_{max}	maximum frequency	see Figure 6							
		V_{CC} = 1.65 V to 1.95 V		100	-	-	80	-	ns
		V_{CC} = 2.3 V to 2.7 V		125	-	-	100	-	ns
		V_{CC} = 2.7 V		150	-	-	120	-	MHz
		V_{CC} = 3.0 V to 3.6 V		150	300	-	120	-	MHz
$t_{sk(o)}$	output skew time	V_{CC} = 3.0 V to 3.6 V	[3]	-	-	1.0	-	1.5	ns
C_{PD}	power dissipation capacitance	per input; V_I = GND to V_{CC}	[4]						
		V_{CC} = 1.65 V to 1.95 V		-	14.1	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V		-	16.4	-	-	-	pF
		V_{CC} = 3.0 V to 3.6 V		-	18.5	-	-	-	pF

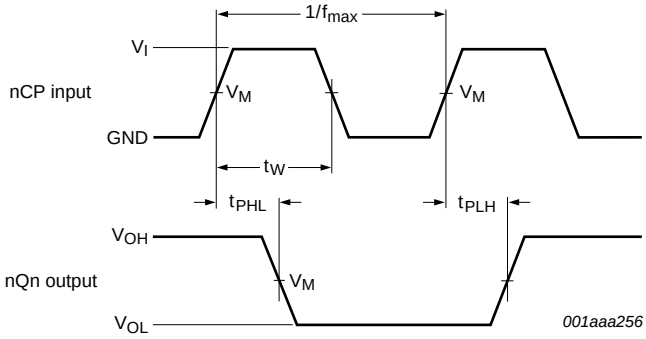
[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
t_{en} is the same as t_{PZL} and t_{PZH}.
t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz; f_o = output frequency in MHz
C_L = output load capacitance in pF
V_{CC} = supply voltage in Volts
N = number of inputs switching
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs

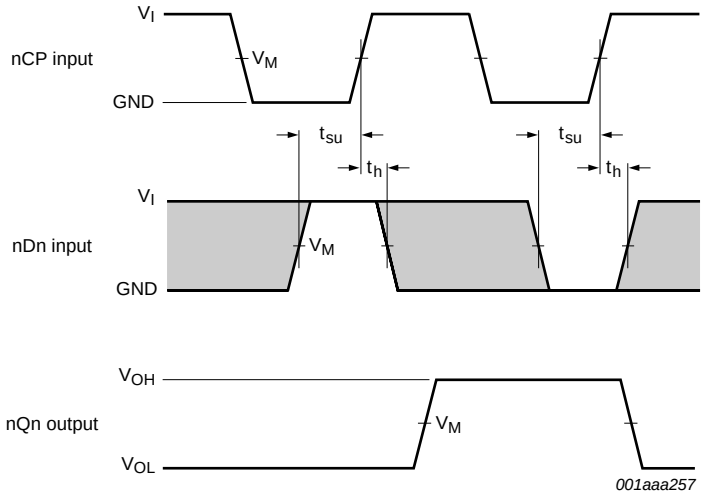
11. Waveforms



Measurement points are given in Table 8.

V_{OL} and V_{OH} are the typical output voltage levels that occur with the output load.

Fig 6. Clock (nCP) to output (nQn) propagation delays, clock pulse width, and the maximum frequency

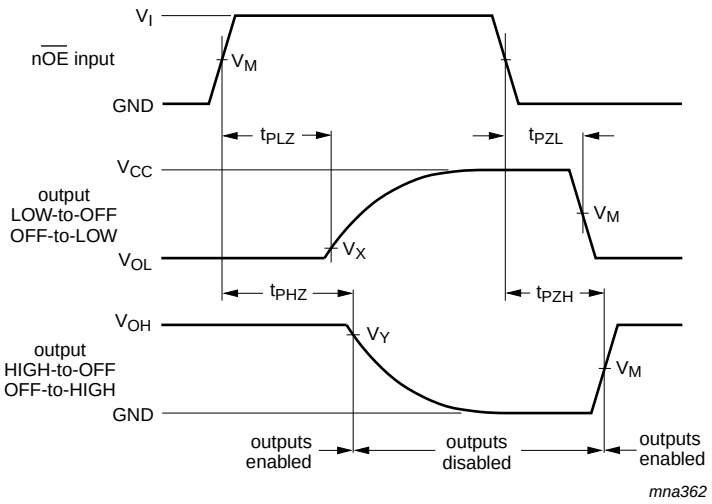


Measurement points are given in Table 8.

The shaded areas indicate when the input is permitted to change for predictable performance.

V_{OL} and V_{OH} are the typical output voltage levels that occur with the output load.

Fig 7. Data set-up and hold times for the nDn input to the nCP input



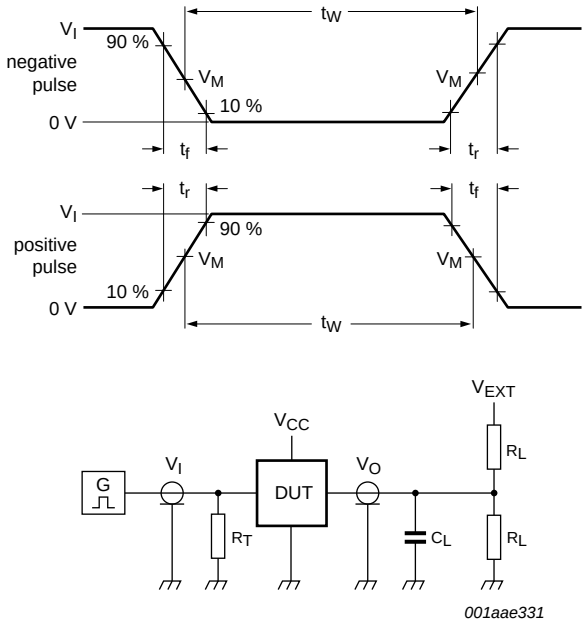
Measurement points are given in Table 8.

V_{OL} and V_{OH} are the typical output voltage levels that occur with the output load.

Fig 8. 3-state enable and disable times

Table 8. Measurement points

Supply voltage	Input		Output		
V_{CC}	V_I	V_M	V_M	V_X	V_Y
1.2 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V_{OL} + 0.15 V	V_{OH} − 0.15 V
1.65 V to 1.95 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V_{OL} + 0.15 V	V_{OH} − 0.15 V
2.3 V to 2.7 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V_{OL} + 0.15 V	V_{OH} − 0.15 V
2.7 V	2.7 V	1.5 V	1.5 V	V_{OL} + 0.3 V	V_{OH} − 0.3 V
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	V_{OL} + 0.3 V	V_{OH} − 0.3 V



Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

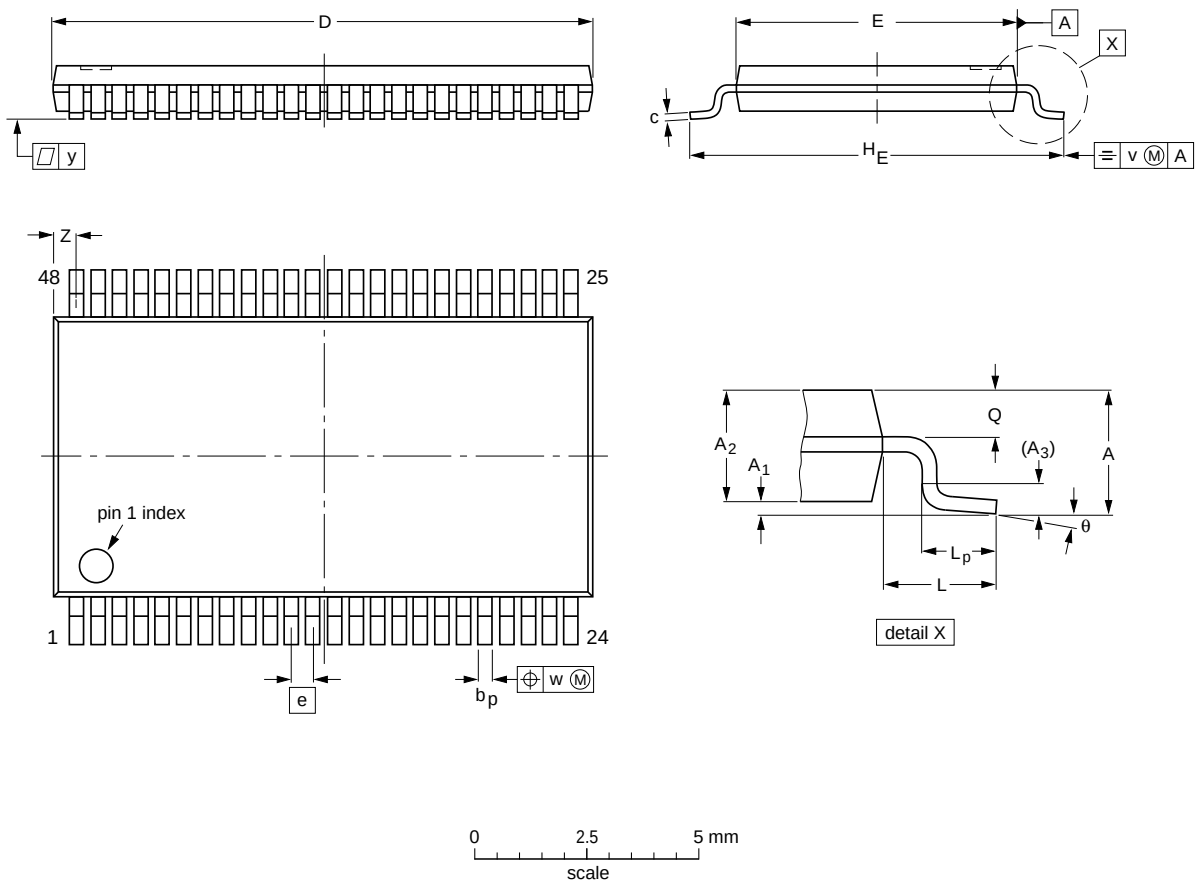
Fig 9. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V_{EXT}		
	V_I	t_r, t_f	C_L	R_L	t_{PLH}, t_{PHL}	t_{PLZ}, t_{PZL}	t_{PHZ}, t_{PZH}
1.2 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	2 × V_{CC}	GND
1.65 V to 1.95 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	2 × V_{CC}	GND
2.3 V to 2.7 V	V_{CC}	≤ 2 ns	30 pF	500 Ω	open	2 × V_{CC}	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2 × V_{CC}	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2 × V_{CC}	GND

12. Package outline

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm **SOT362-1**



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	Q	v	w	y	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8^o 0^o

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT362-1		MO-153				~~99-12-27~~ 03-02-19

Fig 10. Package outline SOT362-1 (TSSOP48)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC_LVCH16374A_Q100 v.1	20130128	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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17. Contents

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